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### Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	6144
Total RAM Bits	36864
Number of I/O	68
Number of Gates	250000
Voltage - Supply	1.14V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/agln250v2-vq100i">https://www.e-xfl.com/product-detail/microchip-technology/agln250v2-vq100i</a>



IGLOO nano Devices	AGLN010	AGLN015 <sup>1</sup>	AGLN020		AGLN060	AGLN125	AGLN250
IGLOO nano-Z Devices <sup>1</sup>				AGLN030Z <sup>1</sup>	AGLN060Z <sup>1</sup>	AGLN125Z <sup>1</sup>	AGLN250Z <sup>1</sup>
Package Pins							
UC/CS	UC36		UC81,	UC81, CS81	CS81	CS81	CS81
QFN	QN48	QN68	CS81	QN48, QN68			
VQFP			QN68	VQ100	VQ100	VQ100	VQ100

Notes:

1. Not recommended for new designs. Few devices/packages are obsoleted. For more information on obsoleted devices/packages, refer to the PDN 1503 - IGLOO nano Z and ProASIC3 nano Z Families.
2. AGLN030 and smaller devices do not support this feature.
3. AGLN060, AGLN125, and AGLN250 in the CS81 package do not support PLLs.
4. For higher densities and support of additional features, refer to the DS0095: IGLOO Low Power Flash FPGAs Datasheet and IGLOOe Low-Power Flash FPGAs Datasheet.

## I/Os Per Package

IGLOO nano Devices	AGLN010	AGLN015 <sup>1</sup>	AGLN020		AGLN060	AGLN125	AGLN250
IGLOO nano-Z Devices <sup>1</sup>				AGLN030Z <sup>1</sup>	AGLN060Z <sup>1</sup>	AGLN125Z <sup>1</sup>	AGLN250Z <sup>1</sup>
Known Good Die	34	—	52	83	71	71	68
UC36	23	—	—	—	—	—	—
QN48	34	—	—	34	—	—	—
QN68	—	49	49	49	—	—	—
UC81	—	—	52	66	—	—	—
CS81	—	—	52	66	60	60	60
VQ100	—	—	—	77	71	71	68

Notes:

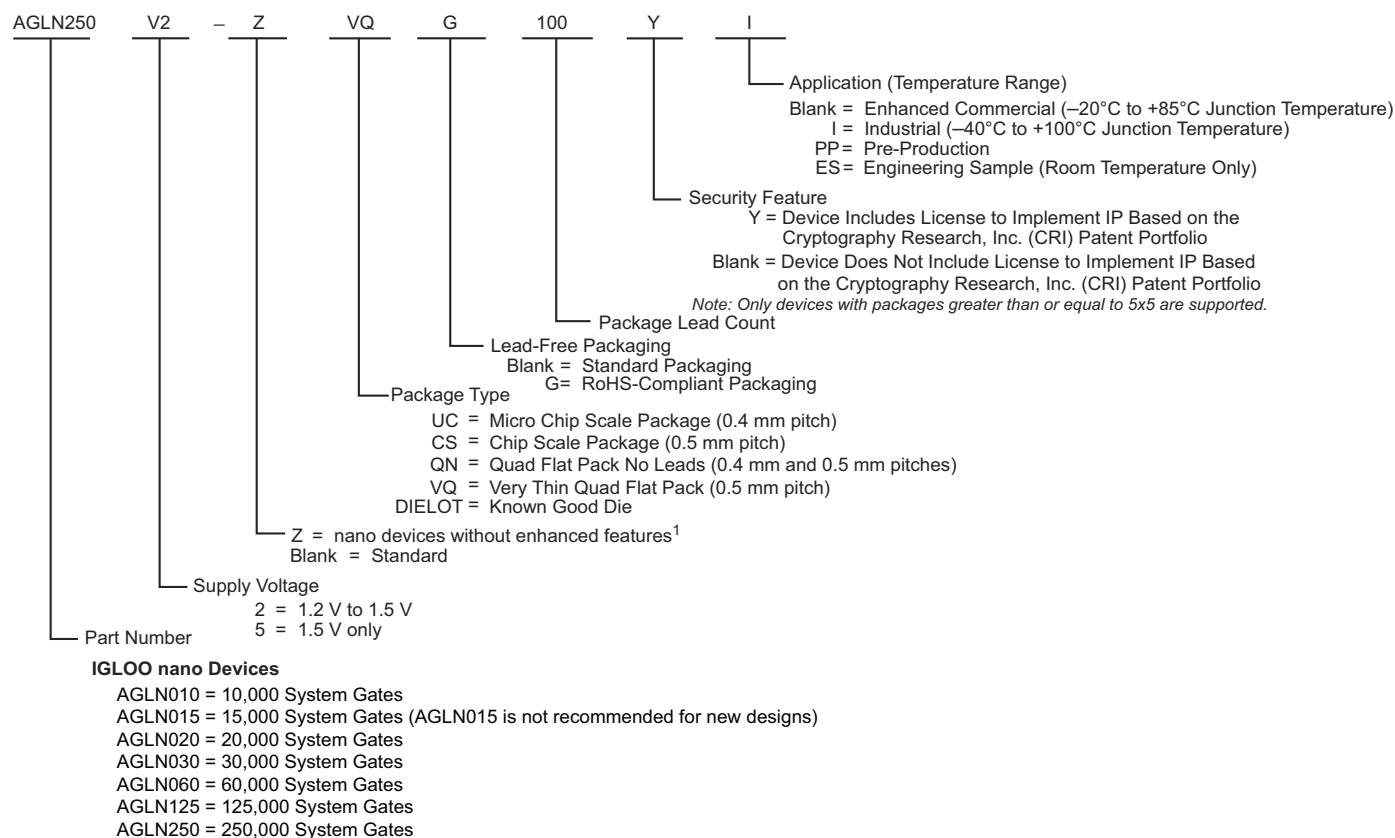
1. Not recommended for new designs.
2. When considering migrating your design to a lower- or higher-density device, refer to the DS0095: IGLOO Low Power Flash FPGAs Datasheet and IGLOO FPGA Fabric User's Guide to ensure compliance with design and board migration requirements.
3. When the Flash\*Freeze pin is used to directly enable Flash\*Freeze mode and not used as a regular I/O, the number of single-ended user I/Os available is reduced by one.
4. "G" indicates RoHS-compliant packages. Refer to "IGLOO nano Ordering Information" on page IV for the location of the "G" in the part number. For nano devices, the VQ100 package is offered in both leaded and RoHS-compliant versions. All other packages are RoHS-compliant only.

**Table 1 • IGLOO nano FPGAs Package Sizes Dimensions**

Packages	UC36	UC81	CS81	QN48	QN68	VQ100
Length × Width (mm\mm)	3 x 3	4 x 4	5 x 5	6 x 6	8 x 8	14 x 14
Nominal Area (mm <sup>2</sup> )	9	16	25	36	64	196
Pitch (mm)	0.4	0.4	0.5	0.4	0.4	0.5
Height (mm)	0.80	0.80	0.80	0.90	0.90	1.20



## IGLOO nano Ordering Information



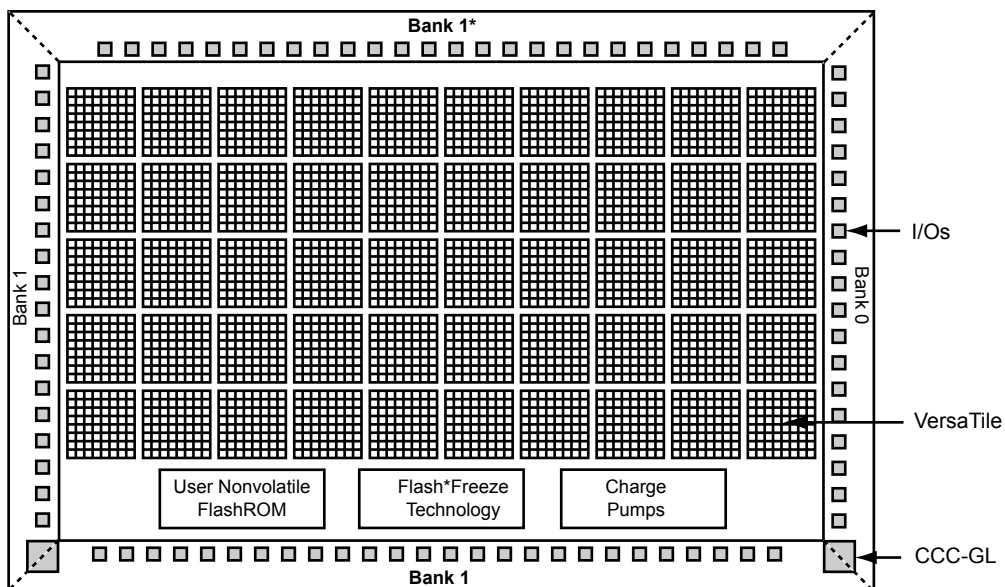
### Notes:

1. Z-feature grade devices AGLN060Z, AGLN125Z, and AGLN250Z do not support the enhanced nano features of Schmitt Trigger input, bus hold (hold previous I/O state in Flash\*Freeze mode), cold-sparing, hot-swap I/O capability and 1.2 V programming. The AGLN030 Z feature grade does not support Schmitt trigger input, bus hold and 1.2 V programming. For the VQ100, CS81, UC81, QN68, and QN48 packages, the Z feature grade and the N part number are not marked on the device. Z feature grade devices are not recommended for new designs.
2. AGLN030 is available in the Z feature grade only.
3. Marking Information: IGLOO nano V2 devices do not have a V2 marking, but IGLOO nano V5 devices are marked with a V5 designator.

## Devices Not Recommended For New Designs

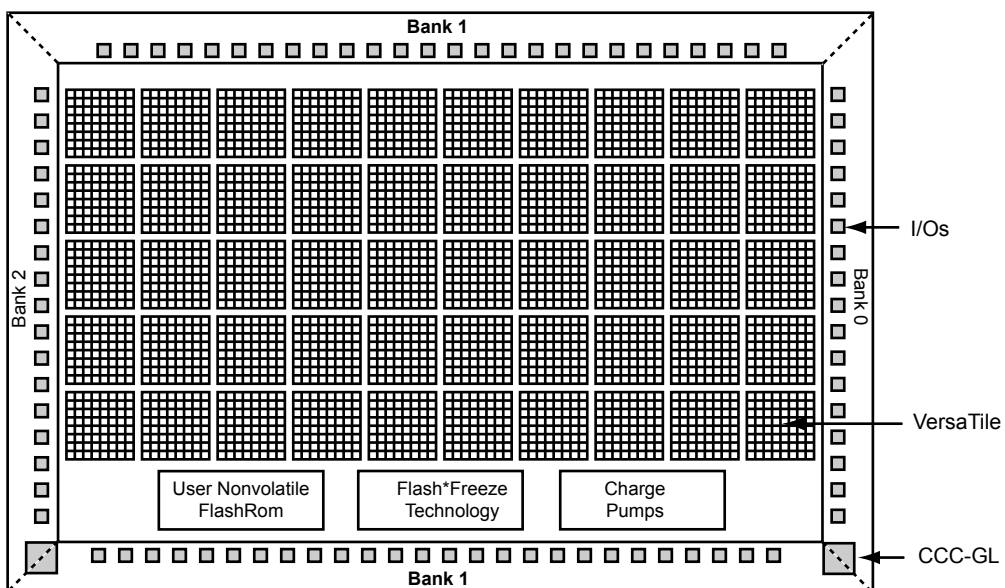
AGLN015, AGLN030Z, AGLN060Z, AGLN125Z, and AGLN250Z are not recommended for new designs. For more information on obsoleted devices/packages, refer to the *PDN1503 - IGLOO nano Z and ProASIC3 nano Z Families*.





Note: \*Bank 0 for the AGLN030 device

**Figure 1-1 • IGLOO Device Architecture Overview with Two I/O Banks and No RAM (AGLN010 and AGLN030)**



**Figure 1-2 • IGLOO Device Architecture Overview with Three I/O Banks and No RAM (AGLN015 and AGLN020)**



## Specifying I/O States During Programming

You can modify the I/O states during programming in FlashPro. In FlashPro, this feature is supported for PDB files generated from Designer v8.5 or greater. See the *FlashPro User's Guide* for more information.

Note: PDB files generated from Designer v8.1 to Designer v8.4 (including all service packs) have limited display of Pin Numbers only.

1. Load a PDB from the FlashPro GUI. You must have a PDB loaded to modify the I/O states during programming.
  2. From the FlashPro GUI, click PDB Configuration. A FlashPoint – Programming File Generator window appears.
  3. Click the Specify I/O States During Programming button to display the Specify I/O States During Programming dialog box.
  4. Sort the pins as desired by clicking any of the column headers to sort the entries by that header. Select the I/Os you wish to modify (Figure 1-7 on page 1-9).
  5. Set the I/O Output State. You can set Basic I/O settings if you want to use the default I/O settings for your pins, or use Custom I/O settings to customize the settings for each pin. Basic I/O state settings:
    - 1 – I/O is set to drive out logic High
    - 0 – I/O is set to drive out logic Low
    - Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming
    - Z -Tri-State: I/O is tristated
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**Figure 1-7 • I/O States During Programming Window**



**Table 2-4 • Overshoot and Undershoot Limits <sup>1</sup>**

<b>VCCI</b>	<b>Average VCCI–GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle<sup>2</sup></b>	<b>Maximum Overshoot/Undershoot<sup>2</sup></b>
2.7 V or less	10%	1.4 V
	5%	1.49 V
3 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

**Notes:**

1. Based on reliability requirements at 85°C.
2. The duration is allowed at one out of six clock cycles. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.

## I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every IGLOO nano device. These circuits ensure easy transition from the powered-off state to the powered-up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 2-1 on page 2-4.

There are five regions to consider during power-up.

IGLOO nano I/Os are activated only if ALL of the following three conditions are met:

1. VCC and VCCI are above the minimum specified trip points (Figure 2-1 and Figure 2-2 on page 2-5).
2. VCCI > VCC – 0.75 V (typical)
3. Chip is in the operating mode.

### **VCCI Trip Point:**

Ramping up (V5 devices): 0.6 V < trip\_point\_up < 1.2 V

Ramping down (V5 devices): 0.5 V < trip\_point\_down < 1.1 V

Ramping up (V2 devices): 0.75 V < trip\_point\_up < 1.05 V

Ramping down (V2 devices): 0.65 V < trip\_point\_down < 0.95 V

### **VCC Trip Point:**

Ramping up (V5 devices): 0.6 V < trip\_point\_up < 1.1 V

Ramping down (V5 devices): 0.5 V < trip\_point\_down < 1.0 V

Ramping up (V2 devices): 0.65 V < trip\_point\_up < 1.05 V

Ramping down (V2 devices): 0.55 V < trip\_point\_down < 0.95 V

VCC and VCCI ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to VCCI.
- JTAG supply, PLL power supplies, and charge pump VPUMP supply have no influence on I/O behavior.



**Table 2-10 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Sleep Mode\***

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
VCCI = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μA
VCCI = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μA
VCCI = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μA
VCCI = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μA
VCCI = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μA

Note:  $*I_{DD} = N_{BANKS} * I_{CCI}$

**Table 2-11 • Quiescent Supply Current (IDD) Characteristics, IGLOO nano Shutdown Mode**

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
Typical (25°C)	1.2 V / 1.5 V	0	0	0	0	0	0	μA

**Table 2-12 • Quiescent Supply Current (IDD), No IGLOO nano Flash\*Freeze Mode<sup>1</sup>**

	Core Voltage	AGLN010	AGLN015	AGLN020	AGLN060	AGLN125	AGLN250	Units
<b>ICCA Current<sup>2</sup></b>								
Typical (25°C)	1.2 V	3.7	5	5	10	13	18	μA
	1.5 V	8	14	14	20	28	44	μA
<b>ICCI or JTAG Current</b>								
VCCI / VJTAG = 1.2 V (per bank) Typical (25°C)	1.2 V	1.7	1.7	1.7	1.7	1.7	1.7	μA
VCCI / VJTAG = 1.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.8	1.8	1.8	1.8	1.8	1.8	μA
VCCI / VJTAG = 1.8 V (per bank) Typical (25°C)	1.2 V / 1.5 V	1.9	1.9	1.9	1.9	1.9	1.9	μA
VCCI / VJTAG = 2.5 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.2	2.2	2.2	2.2	2.2	2.2	μA
VCCI / VJTAG = 3.3 V (per bank) Typical (25°C)	1.2 V / 1.5 V	2.5	2.5	2.5	2.5	2.5	2.5	μA

Notes:

1.  $IDD = N_{BANKS} * ICCI + ICCA$ . JTAG counts as one bank when powered.
2. Includes VCC, VCCPLL, and VPUMP currents.



### **Combinatorial Cells Contribution— $P_{C-CELL}$**

$$P_{C-CELL} = N_{C-CELL} * \alpha_1 / 2 * PAC7 * F_{CLK}$$

$N_{C-CELL}$  is the number of VersaTiles used as combinatorial modules in the design.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-14.

$F_{CLK}$  is the global clock signal frequency.

### **Routing Net Contribution— $P_{NET}$**

$$P_{NET} = (N_{S-CELL} + N_{C-CELL}) * \alpha_1 / 2 * PAC8 * F_{CLK}$$

$N_{S-CELL}$  is the number of VersaTiles used as sequential modules in the design.

$N_{C-CELL}$  is the number of VersaTiles used as combinatorial modules in the design.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in Table 2-19 on page 2-14.

$F_{CLK}$  is the global clock signal frequency.

### **I/O Input Buffer Contribution— $P_{INPUTS}$**

$$P_{INPUTS} = N_{INPUTS} * \alpha_2 / 2 * PAC9 * F_{CLK}$$

$N_{INPUTS}$  is the number of I/O input buffers used in the design.

$\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-14.

$F_{CLK}$  is the global clock signal frequency.

### **I/O Output Buffer Contribution— $P_{OUTPUTS}$**

$$P_{OUTPUTS} = N_{OUTPUTS} * \alpha_2 / 2 * \beta_1 * PAC10 * F_{CLK}$$

$N_{OUTPUTS}$  is the number of I/O output buffers used in the design.

$\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in Table 2-19 on page 2-14.

$\beta_1$  is the I/O buffer enable rate—guidelines are provided in Table 2-20 on page 2-14.

$F_{CLK}$  is the global clock signal frequency.

### **RAM Contribution— $P_{MEMORY}$**

$$P_{MEMORY} = PAC11 * N_{BLOCKS} * F_{READ-CLOCK} * \beta_2 + PAC12 * N_{BLOCK} * F_{WRITE-CLOCK} * \beta_3$$

$N_{BLOCKS}$  is the number of RAM blocks used in the design.

$F_{READ-CLOCK}$  is the memory read clock frequency.

$\beta_2$  is the RAM enable rate for read operations.

$F_{WRITE-CLOCK}$  is the memory write clock frequency.

$\beta_3$  is the RAM enable rate for write operations—guidelines are provided in Table 2-20 on page 2-14.

### **PLL Contribution— $P_{PLL}$**

$$P_{PLL} = PDC4 + PAC13 * F_{CLKOUT}$$

$F_{CLKOUT}$  is the output clock frequency.<sup>1</sup>

1. If a PLL is used to generate more than one output clock, include each output clock in the formula by adding its corresponding contribution ( $PAC13 * F_{CLKOUT}$  product) to the total PLL contribution.



## Overview of I/O Performance

### Summary of I/O DC Input and Output Levels – Default I/O Software Settings

**Table 2-21 • Summary of Maximum and Minimum DC Input and Output Levels**  
Applicable to Commercial and Industrial Conditions—Software Default Settings

I/O Standard	Drive Strength	Equivalent Software Default Drive Strength <sup>2</sup>	Slew Rate	VIL		VIH		VOL	VOH	IOL <sup>1</sup>	IOH <sup>1</sup>
				Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTTL / 3.3 V LVCMOS	8 mA	8 mA	High	–0.3	0.8	2	3.6	0.4	2.4	8	8
3.3 V LVCMOS Wide Range <sup>3</sup>	100 $\mu$ A	8 mA	High	–0.3	0.8	2	3.6	0.2	VCCI – 0.2	100 $\mu$ A	100 $\mu$ A
2.5 V LVCMOS	8 mA	8 mA	High	–0.3	0.7	1.7	3.6	0.7	1.7	8	8
1.8 V LVCMOS	4 mA	4 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	4	4
1.5 V LVCMOS	2 mA	2 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	2	2
1.2 V LVCMOS <sup>4</sup>	1 mA	1 mA	High	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.25 * VCCI	0.75 * VCCI	1	1
1.2 V LVCMOS Wide Range <sup>4,5</sup>	100 $\mu$ A	1 mA	High	–0.3	0.3 * VCCI	0.7 * VCCI	3.6	0.1	VCCI – 0.1	100 $\mu$ A	100 $\mu$ A

Notes:

1. Currents are measured at 85°C junction temperature.
2. The minimum drive strength for any LVCMOS 1.2 V or LVCMOS 3.3 V software configuration when run in wide range is  $\pm 100 \mu$ A. Drive strength displayed in the software is supported for normal range only. For a detailed I/V curve, refer to the IBIS models.
3. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range, as specified in the JESD8-B specification.
4. Applicable to IGLOO nano V2 devices operating at VCCI  $\geq$  VCC.
5. All LVCMOS 1.2 V software macros support LVCMOS 1.2 V wide range, as specified in the JESD8-12 specification.

**Table 2-22 • Summary of Maximum and Minimum DC Input Levels**  
Applicable to Commercial and Industrial Conditions

DC I/O Standards	Commercial <sup>1</sup>		Industrial <sup>2</sup>	
	IIL <sup>3</sup>	IIH <sup>4</sup>	IIL <sup>3</sup>	IIH <sup>4</sup>
	$\mu$ A	$\mu$ A	$\mu$ A	$\mu$ A
3.3 V LVTTTL / 3.3 V LVCMOS	10	10	15	15
3.3 V LVCOMS Wide Range	10	10	15	15
2.5 V LVCMOS	10	10	15	15
1.8 V LVCMOS	10	10	15	15
1.5 V LVCMOS	10	10	15	15
1.2 V LVCMOS <sup>5</sup>	10	10	15	15
1.2 V LVCMOS Wide Range <sup>5</sup>	10	10	15	15

Notes:

1. Commercial range ( $-20^{\circ}\text{C} < T_A < 70^{\circ}\text{C}$ )
2. Industrial range ( $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ )
3.  $I_{IH}$  is the input leakage current per I/O pin over recommended operating conditions, where  $V_{IH} < V_{IN} < V_{CCI}$ . Input current is larger when operating outside recommended ranges.
4.  $I_{IL}$  is the input leakage current per I/O pin over recommended operating conditions, where  $-0.3 \text{ V} < V_{IN} < V_{IL}$ .
5. Applicable to IGLOO nano V2 devices operating at VCCI  $\geq$  VCC.



## Summary of I/O Timing Characteristics – Default I/O Software Settings

**Table 2-23 • Summary of AC Measuring Points**

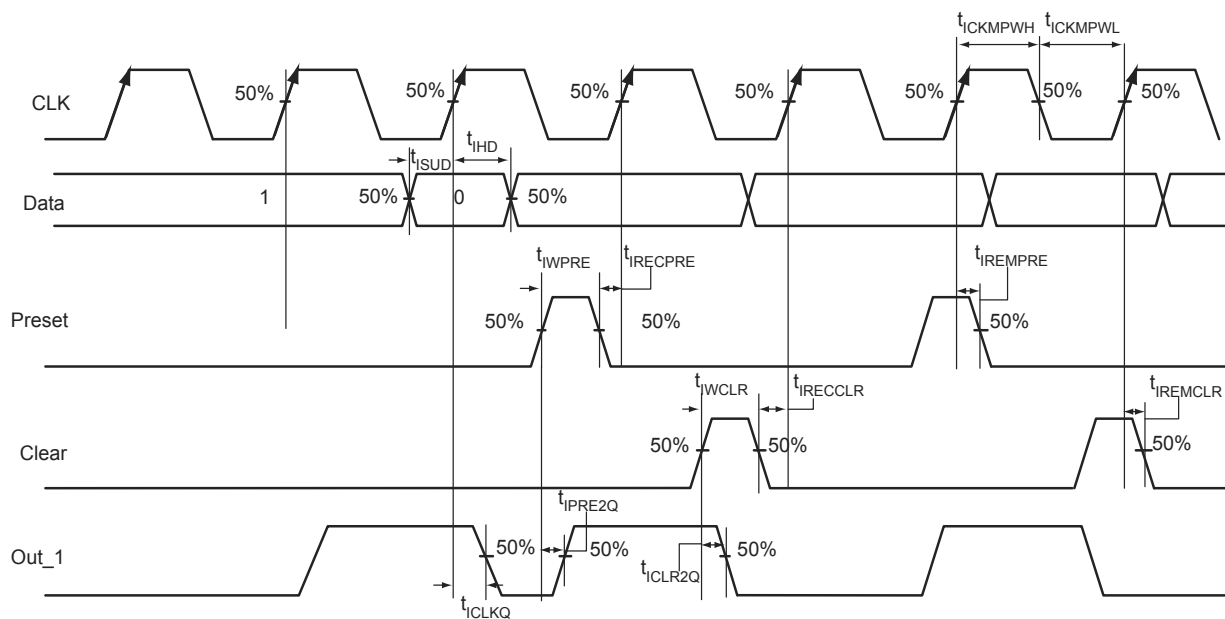
Standard	Measuring Trip Point (Vtrip)
3.3 V LVTTTL / 3.3 V LVCMOS	1.4 V
3.3 V LVCMOS Wide Range	1.4 V
2.5 V LVCMOS	1.2 V
1.8 V LVCMOS	0.90 V
1.5 V LVCMOS	0.75 V
1.2 V LVCMOS	0.60 V
1.2 V LVCMOS Wide Range	0.60 V

**Table 2-24 • I/O AC Parameter Definitions**

Parameter	Parameter Definition
$t_{DP}$	Data to Pad delay through the Output Buffer
$t_{PY}$	Pad to Data delay through the Input Buffer
$t_{DOUT}$	Data to Output Buffer delay through the I/O interface
$t_{EOUT}$	Enable to Output Buffer Tristate Control delay through the I/O interface
$t_{DIN}$	Input Buffer to Data delay through the I/O interface
$t_{HZ}$	Enable to Pad delay through the Output Buffer—HIGH to Z
$t_{ZH}$	Enable to Pad delay through the Output Buffer—Z to HIGH
$t_{LZ}$	Enable to Pad delay through the Output Buffer—LOW to Z
$t_{ZL}$	Enable to Pad delay through the Output Buffer—Z to LOW
$t_{ZHS}$	Enable to Pad delay through the Output Buffer with delayed enable—Z to HIGH
$t_{ZLS}$	Enable to Pad delay through the Output Buffer with delayed enable—Z to LOW



## Input Register



**Figure 2-14 • Input Register Timing Diagram**

### Timing Characteristics

1.5 V DC Core Voltage

**Table 2-72 • Input Data Register Propagation Delays**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$

Parameter	Description	Std.	Units
$t_{\text{CLKQ}}$	Clock-to-Q of the Input Data Register	0.42	ns
$t_{\text{ISUD}}$	Data Setup Time for the Input Data Register	0.47	ns
$t_{\text{IHD}}$	Data Hold Time for the Input Data Register	0.00	ns
$t_{\text{CLR2Q}}$	Asynchronous Clear-to-Q of the Input Data Register	0.79	ns
$t_{\text{PRE2Q}}$	Asynchronous Preset-to-Q of the Input Data Register	0.79	ns
$t_{\text{REMCLR}}$	Asynchronous Clear Removal Time for the Input Data Register	0.00	ns
$t_{\text{RECCLR}}$	Asynchronous Clear Recovery Time for the Input Data Register	0.24	ns
$t_{\text{REMPRE}}$	Asynchronous Preset Removal Time for the Input Data Register	0.00	ns
$t_{\text{RECPRE}}$	Asynchronous Preset Recovery Time for the Input Data Register	0.24	ns
$t_{\text{WCLR}}$	Asynchronous Clear Minimum Pulse Width for the Input Data Register	0.19	ns
$t_{\text{WPRE}}$	Asynchronous Preset Minimum Pulse Width for the Input Data Register	0.19	ns
$t_{\text{CKMPWH}}$	Clock Minimum Pulse Width HIGH for the Input Data Register	0.31	ns
$t_{\text{CKMPWL}}$	Clock Minimum Pulse Width LOW for the Input Data Register	0.28	ns

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



## Timing Characteristics

### 1.5 V DC Core Voltage

**Table 2-84 • Combinatorial Cell Propagation Delays**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.425\text{ V}$

Combinatorial Cell	Equation	Parameter	Std.	Units
INV	$Y = !A$	$t_{PD}$	0.76	ns
AND2	$Y = A \cdot B$	$t_{PD}$	0.87	ns
NAND2	$Y = !(A \cdot B)$	$t_{PD}$	0.91	ns
OR2	$Y = A + B$	$t_{PD}$	0.90	ns
NOR2	$Y = !(A + B)$	$t_{PD}$	0.94	ns
XOR2	$Y = A \oplus B$	$t_{PD}$	1.39	ns
MAJ3	$Y = \text{MAJ}(A, B, C)$	$t_{PD}$	1.44	ns
XOR3	$Y = A \oplus B \oplus C$	$t_{PD}$	1.60	ns
MUX2	$Y = A !S + B S$	$t_{PD}$	1.17	ns
AND3	$Y = A \cdot B \cdot C$	$t_{PD}$	1.18	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

### 1.2 V DC Core Voltage

**Table 2-85 • Combinatorial Cell Propagation Delays**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.14\text{ V}$

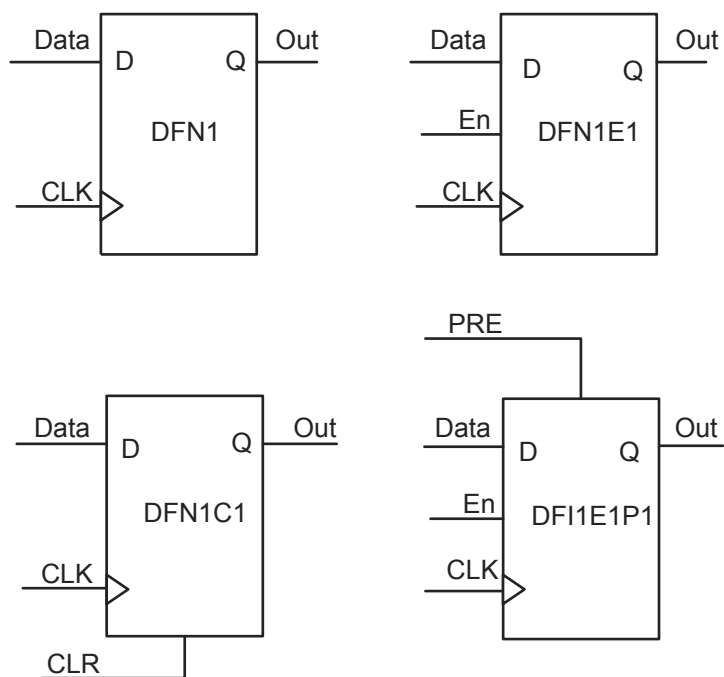
Combinatorial Cell	Equation	Parameter	Std.	Units
INV	$Y = !A$	$t_{PD}$	1.33	ns
AND2	$Y = A \cdot B$	$t_{PD}$	1.48	ns
NAND2	$Y = !(A \cdot B)$	$t_{PD}$	1.58	ns
OR2	$Y = A + B$	$t_{PD}$	1.53	ns
NOR2	$Y = !(A + B)$	$t_{PD}$	1.63	ns
XOR2	$Y = A \oplus B$	$t_{PD}$	2.34	ns
MAJ3	$Y = \text{MAJ}(A, B, C)$	$t_{PD}$	2.59	ns
XOR3	$Y = A \oplus B \oplus C$	$t_{PD}$	2.74	ns
MUX2	$Y = A !S + B S$	$t_{PD}$	2.03	ns
AND3	$Y = A \cdot B \cdot C$	$t_{PD}$	2.11	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.



## VersaTile Specifications as a Sequential Module

The IGLOO nano library offers a wide variety of sequential cells, including flip-flops and latches. Each has a data input and optional enable, clear, or preset. In this section, timing characteristics are presented for a representative sample from the library. For more details, refer to the *IGLOO, ProASIC3, SmartFusion and Fusion Macro Library Guide for Software v10.1*.



**Figure 2-23 • Sample of Sequential Cells**



## 1.2 V DC Core Voltage

**Table 2-87 • Register Delays**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ , Worst-Case  $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.	Units
$t_{CLKQ}$	Clock-to-Q of the Core Register	1.61	ns
$t_{SUD}$	Data Setup Time for the Core Register	1.17	ns
$t_{HD}$	Data Hold Time for the Core Register	0.00	ns
$t_{SUE}$	Enable Setup Time for the Core Register	1.29	ns
$t_{HE}$	Enable Hold Time for the Core Register	0.00	ns
$t_{CLR2Q}$	Asynchronous Clear-to-Q of the Core Register	0.87	ns
$t_{PRE2Q}$	Asynchronous Preset-to-Q of the Core Register	0.89	ns
$t_{REMCLR}$	Asynchronous Clear Removal Time for the Core Register	0.00	ns
$t_{RECCLR}$	Asynchronous Clear Recovery Time for the Core Register	0.24	ns
$t_{REMPRE}$	Asynchronous Preset Removal Time for the Core Register	0.00	ns
$t_{RECPRE}$	Asynchronous Preset Recovery Time for the Core Register	0.24	ns
$t_{WCLR}$	Asynchronous Clear Minimum Pulse Width for the Core Register	0.46	ns
$t_{WPRE}$	Asynchronous Preset Minimum Pulse Width for the Core Register	0.46	ns
$t_{CKMPWH}$	Clock Minimum Pulse Width HIGH for the Core Register	0.95	ns
$t_{CKMPWL}$	Clock Minimum Pulse Width LOW for the Core Register	0.95	ns

*Note:* For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.



### 1.2 V DC Core Voltage

**Table 2-94 • AGLN010 Global Resource**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ ,  $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.		Units
		Min. <sup>1</sup>	Max. <sup>2</sup>	
$t_{RCKL}$	Input Low Delay for Global Clock	1.71	2.09	ns
$t_{RCKH}$	Input High Delay for Global Clock	1.78	2.31	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	1.40		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	1.65		ns
$t_{RCKSW}$	Maximum Skew for Global Clock		0.53	ns

**Notes:**

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.

**Table 2-95 • AGLN015 Global Resource**  
Commercial-Case Conditions:  $T_J = 70^\circ\text{C}$ ,  $V_{CC} = 1.14\text{ V}$

Parameter	Description	Std.		Units
		Min. <sup>1</sup>	Max. <sup>2</sup>	
$t_{RCKL}$	Input Low Delay for Global Clock	1.81	2.26	ns
$t_{RCKH}$	Input High Delay for Global Clock	1.90	2.51	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock	1.40		ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock	1.65		ns
$t_{RCKSW}$	Maximum Skew for Global Clock		0.61	ns

**Notes:**

1. Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).
2. Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).
3. For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-7 for derating values.



should be treated as a sensitive asynchronous signal. When defining pin placement and board layout, simultaneously switching outputs (SSOs) and their effects on sensitive asynchronous pins must be considered.

Unused FF or I/O pins are tristated with weak pull-up. This default configuration applies to both Flash\*Freeze mode and normal operation mode. No user intervention is required.

Table 3-1 shows the Flash\*Freeze pin location on the available packages for IGLOO nano devices. The Flash\*Freeze pin location is independent of device (except for a PQ208 package), allowing migration to larger or smaller IGLOO nano devices while maintaining the same pin location on the board. Refer to the "Flash\*Freeze Technology and Low Power Modes" chapter of the *IGLOO nano FPGA Fabric User's Guide* for more information on I/O states during Flash\*Freeze mode.

**Table 3-1 • Flash\*Freeze Pin Locations for IGLOO nano Devices**

Package	Flash*Freeze Pin
CS81/UC81	H2
QN48	14
QN68	18
VQ100	27
UC36	E2

## JTAG Pins

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

### TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500  $\Omega$  to 1 k $\Omega$  will satisfy the requirements. Refer to Table 3-2 for more information.

**Table 3-2 • Recommended Tie-Off Values for the TCK and TRST Pins**

VJTAG	Tie-Off Resistance <sup>1,2</sup>
VJTAG at 3.3 V	200 $\Omega$ to 1 k $\Omega$
VJTAG at 2.5 V	200 $\Omega$ to 1 k $\Omega$
VJTAG at 1.8 V	500 $\Omega$ to 1 k $\Omega$
VJTAG at 1.5 V	500 $\Omega$ to 1 k $\Omega$

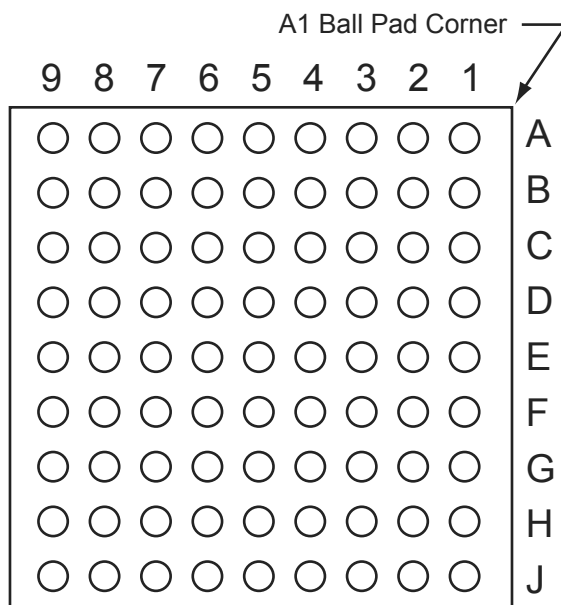
Notes:

1. The TCK pin can be pulled-up or pulled-down.
2. The TRST pin is pulled-down.
3. Equivalent parallel resistance if more than one device is on the JTAG chain



## CS81

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*Note: This is the bottom view of the package.*

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### **Note**

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>.



CS81	
Pin Number	AGLN125Z Function
A1	GAA0/IO00RSB0
A2	GAA1/IO01RSB0
A3	GAC0/IO04RSB0
A4	IO13RSB0
A5	IO22RSB0
A6	IO32RSB0
A7	GBB0/IO37RSB0
A8	GBA1/IO40RSB0
A9	GBA2/IO41RSB0
B1	GAA2/IO132RSB1
B2	GAB0/IO02RSB0
B3	GAC1/IO05RSB0
B4	IO11RSB0
B5	IO25RSB0
B6	GBC0/IO35RSB0
B7	GBB1/IO38RSB0
B8	IO42RSB0
B9	GBB2/IO43RSB0
C1	GAB2/IO130RSB1
C2	IO131RSB1
C3	GND
C4	IO15RSB0
C5	IO28RSB0
C6	GND
C7	GBA0/IO39RSB0
C8	GBC2/IO45RSB0
C9	IO47RSB0
D1	GAC2/IO128RSB1
D2	IO129RSB1
D3	GFA2/IO117RSB1
D4	VCC
D5	VCCIB0
D6	GND
D7	GCC2/IO59RSB0
D8	GCC1/IO51RSB0
D9	GCC0/IO52RSB0

CS81	
Pin Number	AGLN125Z Function
E1	GFB0/IO120RSB1
E2	GFB1/IO121RSB1
E3	GFA1/IO118RSB1
E4	VCCIB1
E5	VCC
E6	VCCIB0
E7	GCA0/IO56RSB0
E8	GCA1/IO55RSB0
E9	GCB2/IO58RSB0
F1*	VCCPLF
F2*	VCOMPLF
F3	GND
F4	GND
F5	VCCIB1
F6	GND
F7	GDA1/IO65RSB0
F8	GDC1/IO61RSB0
F9	GDC0/IO62RSB0
G1	GEA0/IO104RSB1
G2	GEC0/IO108RSB1
G3	GEB1/IO107RSB1
G4	IO96RSB1
G5	IO92RSB1
G6	IO72RSB1
G7	GDB2/IO68RSB1
G8	VJTAG
G9	TRST
H1	GEA1/IO105RSB1
H2	FF/GEB2/IO102RSB1
H3	IO99RSB1
H4	IO94RSB1
H5	IO91RSB1
H6	IO81RSB1
H7	GDA2/IO67RSB1
H8	TDI
H9	TDO

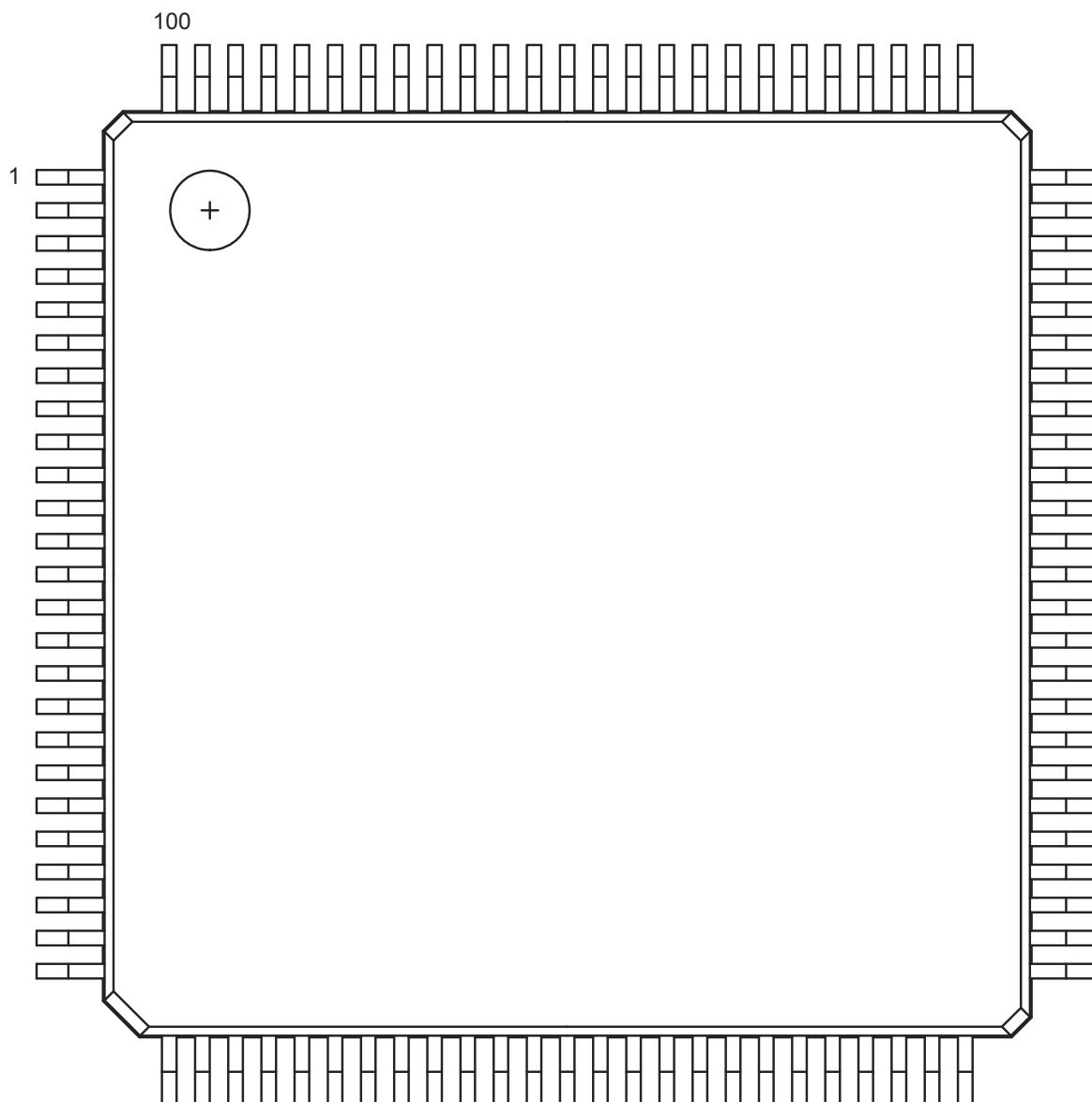
CS81	
Pin Number	AGLN125Z Function
J1	GEA2/IO103RSB1
J2	GEC2/IO101RSB1
J3	IO97RSB1
J4	IO93RSB1
J5	IO90RSB1
J6	IO78RSB1
J7	TCK
J8	TMS
J9	VPUMP

Note: \* Pin numbers F1 and F2 must be connected to ground because a PLL is not supported for AGLN125Z-CS81.



## VQ100

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*Note:* This is the top view of the package.

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### **Note**

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.microsemi.com/soc/products/solutions/package/docs.aspx>.



VQ100	
Pin Number	AGLN030Z Function
1	GND
2	IO82RSB1
3	IO81RSB1
4	IO80RSB1
5	IO79RSB1
6	IO78RSB1
7	IO77RSB1
8	IO76RSB1
9	GND
10	IO75RSB1
11	IO74RSB1
12	GEC0/IO73RSB1
13	GEA0/IO72RSB1
14	GEB0/IO71RSB1
15	IO70RSB1
16	IO69RSB1
17	VCC
18	VCCIB1
19	IO68RSB1
20	IO67RSB1
21	IO66RSB1
22	IO65RSB1
23	IO64RSB1
24	IO63RSB1
25	IO62RSB1
26	IO61RSB1
27	FF/IO60RSB1
28	IO59RSB1
29	IO58RSB1
30	IO57RSB1
31	IO56RSB1
32	IO55RSB1
33	IO54RSB1
34	IO53RSB1
35	IO52RSB1

VQ100	
Pin Number	AGLN030Z Function
36	IO51RSB1
37	VCC
38	GND
39	VCCIB1
40	IO49RSB1
41	IO47RSB1
42	IO46RSB1
43	IO45RSB1
44	IO44RSB1
45	IO43RSB1
46	IO42RSB1
47	TCK
48	TDI
49	TMS
50	NC
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	IO41RSB0
58	IO40RSB0
59	IO39RSB0
60	IO38RSB0
61	IO37RSB0
62	IO36RSB0
63	GDB0/IO34RSB0
64	GDA0/IO33RSB0
65	GDC0/IO32RSB0
66	VCCIB0
67	GND
68	VCC
69	IO31RSB0
70	IO30RSB0

VQ100	
Pin Number	AGLN030Z Function
71	IO29RSB0
72	IO28RSB0
73	IO27RSB0
74	IO26RSB0
75	IO25RSB0
76	IO24RSB0
77	IO23RSB0
78	IO22RSB0
79	IO21RSB0
80	IO20RSB0
81	IO19RSB0
82	IO18RSB0
83	IO17RSB0
84	IO16RSB0
85	IO15RSB0
86	IO14RSB0
87	VCCIB0
88	GND
89	VCC
90	IO12RSB0
91	IO10RSB0
92	IO08RSB0
93	IO07RSB0
94	IO06RSB0
95	IO05RSB0
96	IO04RSB0
97	IO03RSB0
98	IO02RSB0
99	IO01RSB0
100	IO00RSB0



VQ100	
Pin Number	AGLN125 Function
1	GND
2	GAA2/IO67RSB1
3	IO68RSB1
4	GAB2/IO69RSB1
5	IO132RSB1
6	GAC2/IO131RSB1
7	IO130RSB1
8	IO129RSB1
9	GND
10	GFB1/IO124RSB1
11	GFB0/IO123RSB1
12	VCOMPLF
13	GFA0/IO122RSB1
14	VCCPLF
15	GFA1/IO121RSB1
16	GFA2/IO120RSB1
17	VCC
18	VCCIB1
19	GEC0/IO111RSB1
20	GEB1/IO110RSB1
21	GEB0/IO109RSB1
22	GEA1/IO108RSB1
23	GEA0/IO107RSB1
24	VMV1
25	GNDQ
26	GEA2/IO106RSB1
27	FF/GEB2/IO105RSB1
28	GEC2/IO104RSB1
29	IO102RSB1
30	IO100RSB1
31	IO99RSB1
32	IO97RSB1
33	IO96RSB1
34	IO95RSB1
35	IO94RSB1
36	IO93RSB1

VQ100	
Pin Number	AGLN125 Function
37	VCC
38	GND
39	VCCIB1
40	IO87RSB1
41	IO84RSB1
42	IO81RSB1
43	IO75RSB1
44	GDC2/IO72RSB1
45	GDB2/IO71RSB1
46	GDA2/IO70RSB1
47	TCK
48	TDI
49	TMS
50	VMV1
51	GND
52	VPUMP
53	NC
54	TDO
55	TRST
56	VJTAG
57	GDA1/IO65RSB0
58	GDC0/IO62RSB0
59	GDC1/IO61RSB0
60	GCC2/IO59RSB0
61	GCB2/IO58RSB0
62	GCA0/IO56RSB0
63	GCA1/IO55RSB0
64	GCC0/IO52RSB0
65	GCC1/IO51RSB0
66	VCCIB0
67	GND
68	VCC
69	IO47RSB0
70	GBC2/IO45RSB0
71	GBB2/IO43RSB0
72	IO42RSB0

VQ100	
Pin Number	AGLN125 Function
73	GBA2/IO41RSB0
74	VMV0
75	GNDQ
76	GBA1/IO40RSB0
77	GBA0/IO39RSB0
78	GBB1/IO38RSB0
79	GBB0/IO37RSB0
80	GBC1/IO36RSB0
81	GBC0/IO35RSB0
82	IO32RSB0
83	IO28RSB0
84	IO25RSB0
85	IO22RSB0
86	IO19RSB0
87	VCCIB0
88	GND
89	VCC
90	IO15RSB0
91	IO13RSB0
92	IO11RSB0
93	IO09RSB0
94	IO07RSB0
95	GAC1/IO05RSB0
96	GAC0/IO04RSB0
97	GAB1/IO03RSB0
98	GAB0/IO02RSB0
99	GAA1/IO01RSB0
100	GAA0/IO00RSB0